74HC175-Q100; 74HCT175-Q100

Quad D-type flip-flop with reset; positive-edge trigger

Rev. 2 — 4 February 2021 Product data sheet

1. General description

The 74HC175-Q100; 74HCT175-Q100 are quad positive edge-triggered D-type flip-flops with individual data inputs (Dn) and both Qn and $\overline{Q}n$ outputs. The common clock (CP) and master reset (\overline{MR}) inputs load and reset all flip-flops simultaneously. The D-input that meets the set-up and hold time requirements on the LOW-to-HIGH clock transition is stored in the flip-flop and appears at the Q output. A LOW on \overline{MR} causes the flip-flops and outputs to be reset LOW.

The device is useful for applications where both the true and complement outputs are required and the clock and master reset are common to all storage elements.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- · Input levels:
 - For 74HC175-Q100: CMOS level
 - For 74HCT175-Q100: TTL level
- Four edge-triggered D-type flip-flops
- Asynchronous master reset
- Complies with JEDEC standard no. 7A
- ESD protection:
 - MIL-STD-883, method 3015 exceeds 2000 V
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)

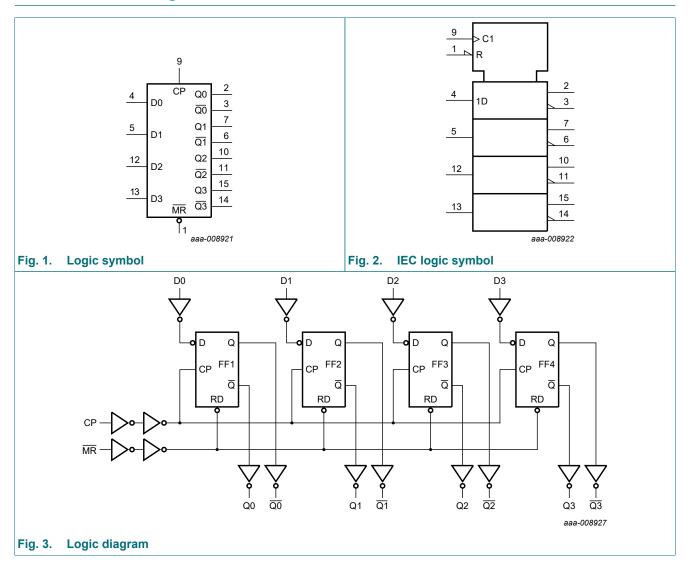
3. Ordering information

Table 1. Ordering information

Type number	Package								
	Temperature range Name Description Ve								
74HC175D-Q100	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads;	SOT109-1					
74HCT175D-Q100			body width 3.9 mm						
74HC175PW-Q100	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads;	SOT403-1					
74HCT175PW-Q100			body width 4.4 mm						

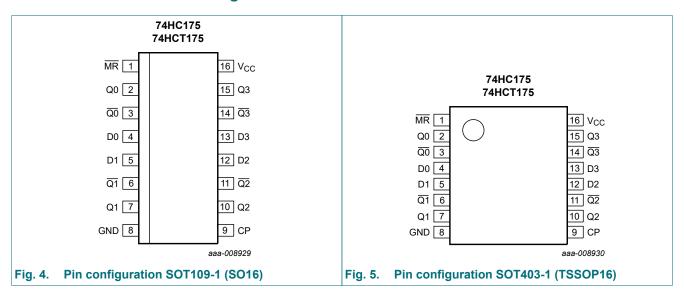


4. Functional diagram



5. Pinning information

5.1. Pinning



5.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
MR	1	asynchronous master reset input (active LOW)
Q0 to Q3	2, 7, 10, 15	flip-flop output
Q0 to Q3	3, 6, 11, 14	complementary flip-flop output
D0 to D3	4, 5, 12, 13	data input
GND	8	ground (0 V)
СР	9	clock input (LOW-to-HIGH edge-triggered)
V _{CC}	16	positive supply voltage

6. Functional description

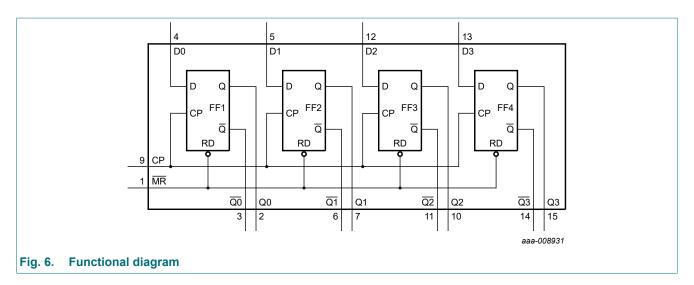
Table 3. Function table

H = HIGH voltage level; h = HIGH voltage level one set-up time prior to the LOW-to-HIGH clock transition;

L = LOW voltage level; I = LOW voltage level one set-up time prior to the LOW-to-HIGH clock transition;

 $X = don't \ care; \uparrow = LOW-to-HIGH \ clock \ transition.$

Operating modes	Inputs		Outputs		
	MR CP Dn		Qn	Qn	
reset (clear)	L	Х	Х	L	Н
load "1"	Н	1	h	Н	L
load "0"	Н	↑	I	L	Н



7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7	V
I _{IK}	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	-	±20	mA
I _{OK}	output clamping current	$V_{O} < -0.5 \text{ V or } V_{O} > V_{CC} + 0.5 \text{ V}$	-	±20	mA
Io	output current	-0.5 V < V _O < V _{CC} + 0.5 V	-	±25	mA
I _{CC}	supply current		-	50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	T_{amb} = -40 °C to +125 °C [1] -	500	mW

^[1] For SOT109-1 (SO16) package: P_{tot} derates linearly with 12.4 mW/K above 110 °C. For SOT403-1 (TSSOP16) package: P_{tot} derates linearly with 8.5 mW/K above 91 °C.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	ditions 74HC175-Q100		74HCT175-Q100			Unit	
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V _{CC}	0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	-	+125	-40	-	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 2.0 V	-	-	625	-	-	-	ns/V
		V _{CC} = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V _{CC} = 6.0 V	-	-	83	-	-	-	ns/V

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C to	o +85 °C	-40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC17	5-Q100						1		<u>'</u>	
V _{IH}	HIGH-level	V _{CC} = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	V _{CC} = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V
V _{IL}	LOW-level	V _{CC} = 2.0 V	-	0.8	0.5	-	0.5	-	0.5	V
	input voltage	V _{CC} = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V
		V _{CC} = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V
V _{OH}	HIGH-level	V _I = V _{IH} or V _{IL}								
out	output voltage	I _O = -20 μA; V _{CC} = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		I _O = -20 μA; V _{CC} = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		I_{O} = -20 μ A; V_{CC} = 6.0 V		6.0	-	5.9	-	5.9	-	V
		I _O = -4.0 mA; V _{CC} = 4.5 V	3.98	4.32	-	3.84	-	3.7	-	V
		I _O = -5.2 mA; V _{CC} = 6.0 V	5.48	5.81	-	5.34	-	5.2	-	V
V _{OL}	LOW-level	V _I = V _{IH} or V _{IL}								
	output voltage	I _O = 20 μA; V _{CC} = 2.0 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 20 μA; V _{CC} = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 20 μA; V _{CC} = 6.0 V	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.26	-	0.33	-	0.4	V
		I _O = 5.2 mA; V _{CC} = 6.0 V	-	0.16	0.26	-	0.33	-	0.4	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	-	±1	-	±1	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0 \text{ V}$	-	-	8.0	-	80	-	160	μΑ
C _I	input capacitance		-	3.5	-	-	-	-	-	pF

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	1
74HCT1	75-Q100					1	·		'	
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	2.0	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	-	0.8	V
V _{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	I _O = -20 μA	4.4	4.5	-	4.4	-	4.4	-	V
		I _O = -4.0 mA	3.98	4.32	-	3.84	-	3.7	-	V
OL	LOW-level	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	I _O = 20 μA; V _{CC} = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 5.2 mA; V _{CC} = 5.5 V	-	0.15	0.26	-	0.33	-	0.4	V
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±0.1	-	±1	-	±1	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	8.0	-	80	-	160	μΑ
ΔI _{CC}	additional supply current	per input pin; V _I = V _{CC} - 2.1 V; other inputs at V _{CC} or GND; V _{CC} = 4.5 V to 5.5 V								
		Dn input	-	40	144	-	180	-	196	μΑ
		CP input	-	60	216	-	270	-	294	μΑ
		MR input	-	100	360	-	450	-	490	μΑ
C _I	input capacitance		-	3.5	-	-	-	-	-	pF

10. Dynamic characteristics

Table 7. Dynamic characteristics

GND (ground = 0 V); C_L = 50 pF unless otherwise specified; for test circuit, see Fig. 10

Symbol	Parameter	Conditions		25 °C		-40 °C to	+85 °C	-40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC17	5-Q100									
	propagation	CP to Qn, Qn; see Fig. 7 [1]								
	delay	V _{CC} = 2.0 V	-	55	175	-	220	-	265	ns
		V _{CC} = 4.5 V	-	20	35	-	44	-	53	ns
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$	-	17	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	16	30	-	37	-	45	ns
t _{PHL}	HIGH	MR to Qn, Qn; see Fig. 8								
	to LOW propagation	V _{CC} = 2.0 V	-	50	150	-	190	-	225	ns
	delay	V _{CC} = 4.5 V	-	18	30	-	38	-	45	ns
		V _{CC} = 5 V; C _L = 15 pF	-	15	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	14	26	-	33	-	38	ns

Symbol	Parameter	Conditions		25 °C		-40 °C to	o +85 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
t _t	transition	Qn output; see Fig. 7 [2]								
	time	V _{CC} = 2.0 V	-	19	75	-	95	-	110	ns
		V _{CC} = 4.5 V	-	7	15	-	19	-	22	ns
		V _{CC} = 6.0 V	-	6	13	-	16	-	19	ns
t_W	pulse width	CP input HIGH or LOW; see Fig. 7								
		V _{CC} = 2.0 V	80	22	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	8	-	20	-	24	-	ns
		V _{CC} = 6.0 V	14	6	-	17	-	20	-	ns
		MR input LOW; see Fig. 8								
		V _{CC} = 2.0 V	80	19	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	7	-	20	-	24	-	ns
		V _{CC} = 6.0 V	14	6	-	17	-	20	-	ns
t _{rec}	recovery	MR to CP; see Fig. 8								
	time	V _{CC} = 2.0 V	5	-33	-	5	-	5	-	ns
		V _{CC} = 4.5 V	5	-12	-	5	-	5	-	ns
		V _{CC} = 6.0 V	5	-10	-	5	-	5	-	ns
t _{su}	set-up time	Dn to CP; see Fig. 9								
		V _{CC} = 2.0 V	80	3	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	1	-	20	-	24	-	ns
		V _{CC} = 6.0 V	14	1	-	17	-	20	-	ns
t _h	hold time	Dn to CP; see Fig. 9								
		V _{CC} = 2.0 V	25	2	-	30	-	40	-	ns
		V _{CC} = 4.5 V	5	0	-	6	-	8	-	ns
		V _{CC} = 6.0 V	4	0	-	5	-	7	-	ns
f _{max}	maximum	CP input; see Fig. 7								
	frequency	V _{CC} = 2.0 V	6	25	-	4.8	-	4	-	MHz
		V _{CC} = 4.5 V	30	75	-	24	-	20	-	MHz
		V _{CC} = 5 V; C _L = 15 pF	-	83	-	-	-	-	-	MHz
		V _{CC} = 6.0 V	35	89	-	28	-	24	-	MHz
C _{PD}	power dissipation capacitance	per package; $V_I = GND$ to V_{CC} [3]	-	32	-	-	-	-	-	pF

Product data sheet

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HCT1	75-Q100							<u> </u>	-	
t _{pd}	propagation	CP to Qn, Qn; see Fig. 7 [1]								
	delay	V _{CC} = 4.5 V	-	19	33	-	41	-	50	ns
		V _{CC} = 5 V; C _L = 15 pF	-	16	-	-	-	-	-	ns
t _{PHL}	HIGH	MR to Qn; see Fig. 8								
	to LOW	V _{CC} = 4.5 V	-	22	38	-	48	-	57	ns
	propagation delay	V _{CC} = 5 V; C _L = 15 pF	-	19	-	-	-	-	-	ns
		MR to Qn; see Fig. 8								
		V _{CC} = 4.5 V	-	19	35	-	44	-	53	ns
		V _{CC} = 5 V; C _L = 15 pF	-	16	-	-	-	-	-	ns
t _t		Qn output; see Fig. 7 [2]								
	time	V _{CC} = 4.5 V	-	7	15	-	19	-	22	ns
t _W	pulse width	CP input HIGH or LOW; see Fig. 7								
		V _{CC} = 4.5 V	20	12	-	25	-	30	-	ns
		MR input LOW; see Fig. 8								
		V _{CC} = 4.5 V	20	11	-	25	-	30	-	ns
t _{rec}	recovery	MR to CP; see Fig. 8								
	time	V _{CC} = 4.5 V	5	-10	-	5	-	5	-	ns
t _{su}	set-up time	Dn to CP; see Fig. 9								
		V _{CC} = 4.5 V	16	5	-	20	-	24	-	ns
t _h	hold time	Dn to CP; see Fig. 9								
		V _{CC} = 4.5 V	5	0	-	5	-	5	-	ns
f _{max}	maximum	CP input; see Fig. 7								
	frequency	V _{CC} = 4.5 V	25	49	-	20	-	17	-	MHz
		V _{CC} = 5 V; C _L = 15 pF	-	54	-	-	-	-	-	MHz
C _{PD}	power dissipation capacitance	per package; [3] V _I = GND to V _{CC} - 1.5 V	-	34	-	-	-	-	-	pF

- t_{pd} is the same as t_{PHL} and t_{PLH}.
 t_t is the same as t_{THL} and t_{TLH}.
 C_{PD} is used to determine the dynamic power dissipation (P_D in μW).
 P_D = C_{PD} x V_{CC}² x f_i + Σ (C_L x V_{CC}² x f_o) where:
 f_i = input frequency in MHz;

f_o = output frequency in MHz;

 Σ (C_L x V_{CC} 2 x f_o) = sum of outputs;

C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V.

10.1. Waveforms and test circuit

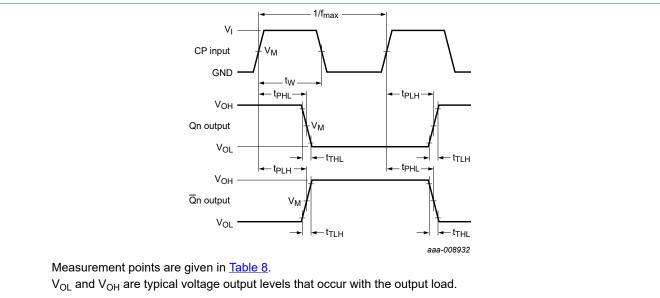


Fig. 7. Input to output propagation delay, output transition time, clock input pulse width and maximum frequency

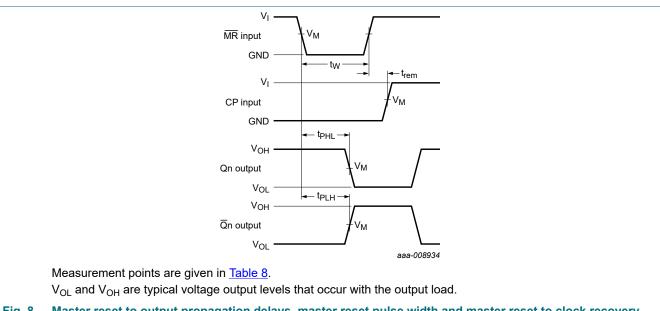
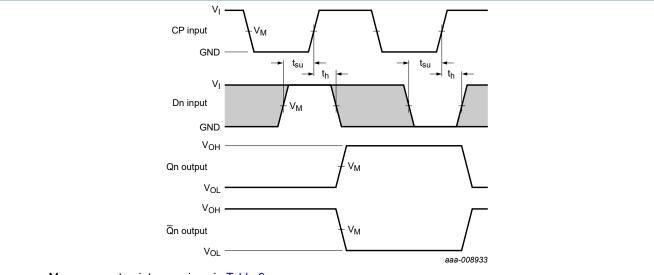


Fig. 8. Master reset to output propagation delays, master reset pulse width and master reset to clock recovery time



Measurement points are given in <u>Table 8</u>.

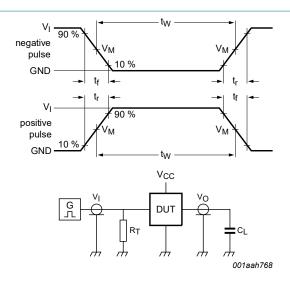
 $\ensuremath{V_{\text{OL}}}$ and $\ensuremath{V_{\text{OH}}}$ are typical voltage output levels that occur with the output load.

The shaded areas indicate when the input is permitted to change for predictable output performance.

Fig. 9. Data set-up and hold times for data input

Table 8. Measurement points

Туре	Input	Output	
	V _I	V _M	V _M
74HC175-Q100	V _{CC}	0.5V _{CC}	0.5V _{CC}
74HCT175-Q100	3 V	1.3 V	1.3 V



Test data is given in Table 9.

Definitions for test circuit:

 R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

 C_L = Load capacitance including jig and probe capacitance.

 R_L = Load resistance.

Fig. 10. Test circuit for measuring switching times

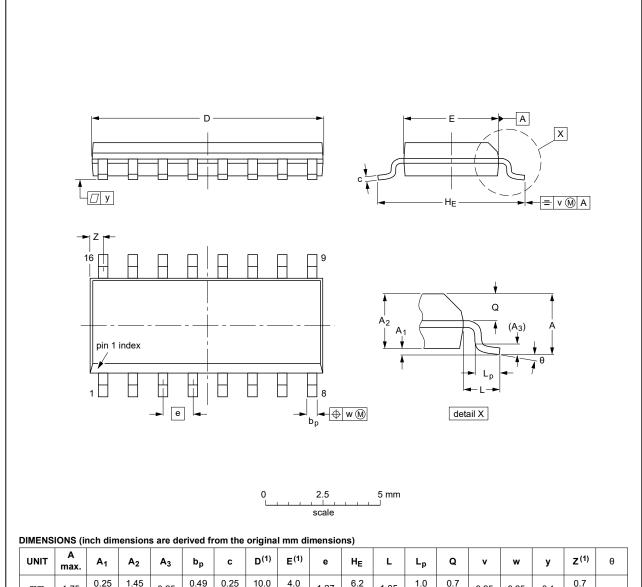
Table 9. Test data

Туре	Input		Load	Test	
	VI	t _r , t _f	C _L	R _L	
74HC175-Q100	V _{CC}	6 ns	15 pF, 50 pF	1 kΩ	t _{PLH} , t _{PHL}
74HCT175-Q100	3 V	6 ns	15 pF, 50 pF	1 kΩ	t _{PLH} , t _{PHL}

11. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	10.0 9.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01		0.0100 0.0075		0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016	0.028 0.020	0.01	0.01	0.004	0.028 0.012	0°

Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT109-1	076E07	MS-012				99-12-27 03-02-19	

Fig. 11. Package outline SOT109-1 (SO16)

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1

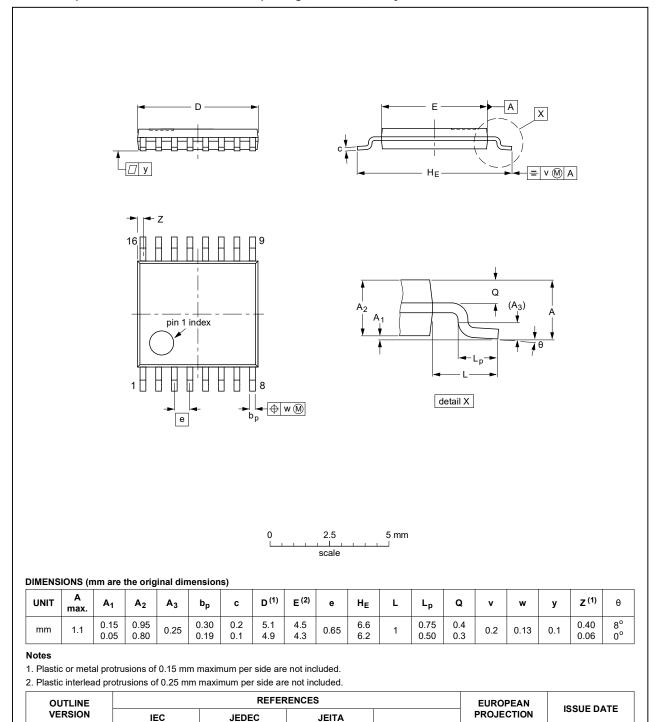


Fig. 12. Package outline SOT403-1 (TSSOP16)

SOT403-1

99-12-27

03-02-18

 \bigcirc

MO-153

12. Abbreviations

Table 10. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MIL	Military
MM	Machine Model
TTL	Transistor-Transistor Logic

13. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
74HC_HCT175_Q100 v.2	20210204	Product data sheet	-	74HC_HCT175_Q100 v.1		
Modifications:	 The format of this data sheet has been redesigned to comply with the identity guidelines Nexperia. Legal texts have been adapted to the new company name where appropriate. Section 7: Derating values for P_{tot} total power dissipation updated. 					
74HC_HCT175_Q100 v.1	20140519	Product data sheet	-	-		

14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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